Basic Comparison Of Fix Capacitor-Thyristor Controlled Reactor, FC-TCR (SVC) And Thyristor Controlled Series Capacitor (TCSC) In Electric Power System

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Abstract: In this work, effort is concentrated on explicit exposure of similarities and differences between FC-TCR and TCSC devices in electric system. Several distinct and common operational features of the two components are addressed and evaluated to build a comprehensive analysis for adequate comparison and contrast of the FACTS controllers. The two different models of the devices that split up their identically composed adjustable parameters (in terms of constituting components) into B_{SVC} and X_{TCSC} are clearly demonstrated in attempt to ex-ray the relative functionalities of the controllers in power system. All the diagrams are very illustrative in picturing out the structural composition of FC-TCR and TCSC equipments in order to point at the obvious similitude of their basic circuit. Apart from the self-explanatory and theoretical preamble that leads the introduction, the nature of the work takes a posture of two-way stance in which the similar and varied characteristics of the controllers are vertically featured; thereby, covering the structural, functional and "installational" comparison; all displayed in a tabular form.

Keywords: Comparison, TCSC, FC-TCR, Electric, System

I. INTRODUCTION

FACTS equipments by IEEE recommendation are categorized into series, shunt and combined series-shunt controllers. Among the series elements of the FACTS family include thyristor controlled series capacitor (TCSC), static synchronous series compensator (SSC) etc.

The series reactance of power lines can be improved upon to meet the system requirement in attempt to enhance the active power flow on the line .In this case; the existing branch voltages are coupled in series with the line so as to achieve optimum power transfer. Similarly, improvement of bus voltages is often by automatic amendment of susceptance of installed shunt component on the bus.

In some cases, direct effect of the improved voltage magnitudes on the network buses stems from the impact of bus connected FACTS components such as shunt controllers – SVC, STATCOM etc and this influence is not monopolized by

the connecting bus areas only; but can be far reaching to other neighboring buses, depending on the reactive power compensation capability of the shunt controllers in question. This augments system voltages in order to eliminate bus voltage deficit.

In a true network operation where the system's high operational efficiency is in great demand, it is seldom having a situation where only a single controller functions to achieve all the network requirements. As a result; agglomeration of the functional input of the three categories is always experienced in order to benefit from the independent properties of each of the FACTS controller family.

Also, Integration of the series and shunt FACTS controllers into a single component for efficient operation of power system can be appropriated from the combination of the two devices out of the two independent categories to form composite equipment known as shunt-series controller. In effect, separate inherent functional characteristics of each of

the constituent members is being harnessed to achieve a better performance that may not be completely offered by one alone, when operating independently from the other in the system. As a result, unified power flow controller (UPFC) can control a host number of system situations in accordance to the behavior of individual constituents of the unit. This is more preferable considering cost implication; especially, when embarking on a large scale system improvement planning.

In sumary, there is always integration of the functional potency of the three classes in the light of accomplished optimum equipment localization within the network; and this to a larger extent helps to induce a high degree of steady and dynamic stability of the power system; thus, establishing a rugged and efficient electrical environment through the system operation under a well electrically instituted conditions such as

- ✓ Proper sub-synchronous resonance (SSR) control
- ✓ A constant electrical fault-free condition
- ✓ Effective power flow control as well as
- ✓ Adequate power oscillation damping within the power system.

FACTS equipment has been defined by IEEE as "AC" transmission system incorporating power electronic based and other static controllers to enhance controllability and increase power transfer. Inclusion of power electronics as the basic components of the equipments suggests the key functional entity of the devices and this is glaring from the control concept of the system. As such, thynistor devices have immensely contributed to the success in usage of FACT controllers, since, the adjustment of the network constants to implement the desired system objectives is necessitated by the power electronic composition. Through a firing and appropriately timed pulses, the right firing angle, α , can be decided for triggering on and off, the thyristor switches. This is done on a considerable level of precautions to avoid operating within the resonance angle, α_{res} and the tendency for system oscillation.

SECTION 1

MODELING OF STATIC VAR COMPENSATOR (SVC) AND THYRISTOR CONTROLLED SERIES CAPACITOR.

THYRISTOR CONTROLLED SERIES CAPACITOR MODEL

The equivalent reactance of the system that is connected with TCSC is the summation of adjustable TCSC reactance, X_{TCSC} and the natural reactance of the system lines, Xitself. Among the components of line reactance are the line charging capacitance and inductance, neglecting the line resistance. Therefore; for a system with installed TCSC component, the equivalent line reactance of the network is as stated below

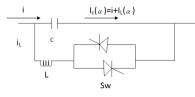


Figure 1.0: Diagram showing line series circuit of an TCSC device

$$= [X_{\text{Line}}(1/\omega_{\mathcal{C}} + \omega L) + 1/\omega_{\mathcal{C}} \cdot \omega L][1/\omega_{\mathcal{C}} + \omega L]^{-1}$$
$$= [X_{\text{Line}}(\frac{\omega^{2}LC+1}{\omega_{\mathcal{C}}}) + \frac{L}{C}][\frac{(\omega^{2}LC+1)}{\omega_{\mathcal{C}}}]^{-1}.....(2)$$

Where,

Xequ. = Equivalent or total reactance on the system.

 X_{Line} = natural line reactance of the system

$$I_{L}(\alpha)(s) = I_{0} B [Sin \omega_{t} - \frac{\omega}{\omega_{0}} Sin \omega_{0} t]....(3)$$

From the basic circuit of figure 1 above, the thyristors of the circuit decide the level of participation of capacitor component for line compensation. The capacitor can be completely bypassed when the thyristor switches are fired at a

suitable angle, α ; then, allowing line current to pass through inductor branch and resulting such expressions as

$$I_{L}(\alpha)(s) = I_{0} B [Sin \omega t - \frac{\omega}{\omega_{0}} Sin \omega_{0} t]....(3)$$

 ω_{0}

(for inductor current)

Full capacitive compensation occurs when SW_1 and SW_2 thyristor are switched off as shown, permitting the current flow through capacitor C only. See the diagram below

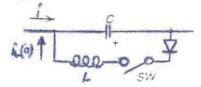


Figure 1.1: Diagram showing the line series TCSC circuit with thyristor component switched off

Therefore; the quantity of current that are allowed to pass through the capacitor determines the extent of charging and discharging of C and the development of voltage magnitude which Is in quadrature with the line current and in series with the line. The voltage expression is as shown below

 $V_{C}(t) = I_{0} X_{C}$ [Cos ω t](4) This largely account for the system reactive power

This largely account for the system reactive power compensation as obtained with thyristor controlled series capacitor (TCSC).

The figure below shows the graph of the equivalent reactance, X_{eq} plotted against the thyristor firing angle, α .

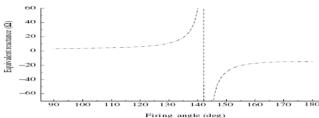


Figure 1.2: Diagram showing the graphical illustration of the dependency of thyristor firing angle on the TCSC equivalent susceptance

The positive half with the curve extending from X_{bypass} ($\alpha = 0$), sweeping across the plane towards the resonance shows the inductive region. The firing angles that are traceable to this curve are the range of angles within which inductive compensation is attainable, with X_{MAX} being the maximum attainable equivalent reactance.

The effectiveness of the equivalent reactance, X_{eq} for TCSC is limited at the resonance point where $\alpha = \alpha_{res}$; and for normal operations, the firing angle must be maintained at a particular length, $\Delta \alpha$ away from the resonance angles α_{res} . This gives room for maximum and minimum reactance (i.e. X_{MAX} . and X_{MIN} .) corresponding to the upper and lower bound of X_{eq} axis respectively. From the graph, at $\alpha = 0$, there is a continuous triggering of the thyristor switches. Thus, the basic circult behaves as a parallel connected L C circuit. This is known as bypass mode. When $0^0 < \alpha < \alpha_{res}$, the angle ranges below the resonance angle, α_{res} but greater than 0^0 ; and at this range, the equivalent reactance, X_{eq} is positive and inductive. This is refereed as inductive boost mode.

In capacitive boost mode, angle α is greater than resonance angle, α_{res} but lesser than 90° (i.e. α_{res} $< \alpha < 90°$). As such the equivalent reactance is negative and capacitive in nature. Subsequently, as the firing angle equals 90°, ($\alpha = 90°$) the thyristor is no more conductive and triggerable. As result, the effect of the fixed capacitor is largely felt on the line and this is called blocking mode.

For static Var Compensator, the adjustment of line parameters is by maneuvering the inductive susceptance of the device, $B_{L(\alpha)}$ which is controllable through the thyristor firing angle to determine the branch current. It is worth knowing that capacitor C is fixed in value and can allow capacitive current into the line depending on SW₁ and SW₂ switching mode. The expression that relates the inductive and capacitive reactance in the circuit can be derived thus:

II. STATIC VAR COMPENSATOR MODELING

In this modeling, a FC-TCR basic circuit which is the same in component composition with the TCSC counterpart is presented; though with absolute incongruity in terms of direction and area of installation in power system, as we can observe comparing the two modeling. As shown below, unlike TCSC equipment; the device occupies the bus through a protective circuit breaker and a shunt transformer to emerge a typical variable susceptance, B_{SVC} assumed as the element of reactive power control for bus voltage improvement. The equivalent susceptance of the device, B_{equ} comprises of thyristor-dependent adjustable inductive susceptance, $B_{L(\alpha)}$ and a fixed capacitive, susceptance, B_{C} ;all mathematically related with the natural constituent variables as shown in the

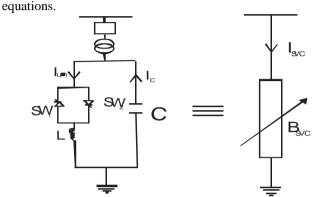


Figure 1.3: Diagrm showing the circuit and inductive susceptance of an FC-TCR device

$$B_{eq} = B_{L(\alpha)} + B_{C}.....(5)$$

$$B_{L(\alpha)} = \frac{-\pi - 2\alpha - \sin 2\alpha}{\omega L \pi}$$

$$B_{C} = -\omega_{C}$$
Therefore,
$$B_{eq} = -\frac{\pi - 2\alpha - \sin 2\alpha}{\omega L \pi} - \omega_{C}$$

$$= -\left[\frac{(\pi + 2\alpha + \sin 2\alpha) + \omega^{2} L C \pi}{\omega L \pi}\right].....(6)$$
Where:

 I_{C} = Capacitive reactive current, $I_{L(\alpha)}$ = Inductive reactive current

 I_{SVC} = SVC net reactive current, B_{SVC} = SVC variable susceptance

L= inductance of the SVC device, C = Fixed capacitor of the device

 B_{eq} = equivalent Susceptance, $B_{L(\alpha)}$ = inductive susceptance

 B_{C} = Capacitive susceptance, SW₁ & SW₂ = thyristor switches

Just as it is obtained in TCSC model, the SVC variable susceptance can also be adjusted for voltage control via the thyristor firring angles which by definition is a delay angle measured from the peak of capacitor voltage to the firing instant. As the reactive power compensation is adversely limited at the resonance angle in TCSC; for SVC, the resonance effect is not a problem; being that the basic modules are shunt connected, it therefore means that the module is discounted; in effect, the unavailable band around zero as can be seen from the graph of equivalent susceptance below is not regarded Therefore, the upper and lower bound (i.e. $B_{SVC(lower)}$) and $B_{SVC(upper)}$) in the graph result the total susceptance which is a function of inductive and capacitive susceptance as expressed above.

From equation (4), the firing angle, α shows the variability of the equivalent susceptance through the two connected thyristor devices. Taking B_{eq} as a susceptance for SVC of a certain bus k and the associated active power at the same bus to be O, the corresponding power flow equation can be expressed as follow:

 Q_{SVC} = - $V_k^2 B_{SVC}$(7) The expression of equation (6) shows the reactive

power, Q_{SVC} as a function of square of bus voltage, V_K and the susceptance, B_{SVC} at bus k. Reactive power demand variation requires a corresponding adjustment of susceptance connected to bus K. This is to eliminate reactive power deficit; thus increasing the supply so as to maintain the bus voltage at the system required level.

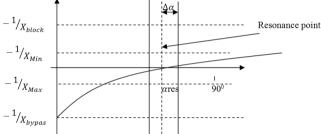


Figure 1.4: Diagram showing the graphical illustration of the dependency of thyristor firing angle on the FC-TCR

equivalent susceptance							
(SVC) FC –	STRUCTURAL		TCSC				
TCR	SIMILARITIES						
1. Presence of TCR branch		TCR branch is also present					
for Reactive power control		for thyristor control action					
 Availability of capacitor device for reactive power injection The basic circuit comprises 		Also, capacitor is available for improvement of line series compensation The basic circuit consists of					
of thyristors in opposite		the same bank of capacitor, a					
direction of connection,		reactor element, two thyristor					
reactor element and a bank of		components connected in					
fixed capacitor		opposite direction to each other					
~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~							
	$\int_{-\infty}^{\infty} i_L(\alpha)$						
Basic circuit diagram of an FC-TCR device		Basic circuit diagram of a TCSC device (the same with FC-TCR device)					

(SVC) FC –		TURAL	TCSC	
TCR		RITIES		
1. FC-TCR is appl	licable in	Pow	er system line	
Reactive power compensation		compensation is		
for enhancement of		accomplishable in series		
system stabi	lity	connection of TCSC with the		
		line in order to improve series		
		line voltages for system		
			stability	
2. With stability in	n electric	Enhanc	ement of system	
power Voltage for a		power potenial is attainable		
enhanced system bus voltage		being that the system line		
status, there is sure tendency			ltage is efficiently	
for a conducive	•		ented to give a	
environment to i		conducive room for optimum		
power transfer potential		power transportation in the		
F • · · · · · · · · · · · · · · ·		face of sy	stem dynamic and	
			state conditions.	
		Libudy		
3.Drastic implication of			ly, generation of	
harmonic Signal in system		harmonic signal is one of the		
owing to association		basic disadvantages of		
fragment as a		association of TCR segment		
constituting member		as the major component		
component			f a TCSC in electric	
5		pov	wer network.	
4. Possibility of	control	Possib	ility of adopting	
through thyristor firing angles		thyristor control mechanism		
for system bus voltage		for power flow regulation		
regulation		-	C	
5. Controllable vi		TCSC can equally be		
control Un	it	controlled using PI control		
к		ĸ	system.	
	K Bsvc	$V_r \longrightarrow \Delta V$	KP+ K X _{TCSC}	
	+	t l		
V _b Antiwi	ndu		Antiwindu	
tend b		hui	P	
The same basic P	I control	The sam	e basic PI control	
System schematic diagram as		System schematic diagram		
with TCSC device		with FC-TCR device		
6 FC TCD adjust	e evetom	maaa	1 66 1	
6.FC-TCR adjusts system		TCSC also effects line		
parameters, in attempt, to		compensation through power		
	1		system parameter adjustment.	
effect reactive		• •		
effect reactive		ΓURAL	TCSC	
effect reactive compensation (SVC) FC – TCR	on STRUCT SIMILA	RITIES		
effect reactive compensation (SVC) FC – TCR There is no ob	on STRUCT SIMILA	RITIES tural dissim	ilarity in terms of	
effect reactive compensation (SVC) FC – TCR There is no ob component compose	STRUCT SIMILA SIMILA Sition betwe	RITIES tural dissim en thyristor	ilarity in terms of r controlled series	
effect reactive compensation (SVC) FC – TCR There is no ob	STRUCT SIMILA Divious struct sition betwee ad fix-capaci	RITIES tural dissim en thyristor itor thyristor	ilarity in terms of controlled series controlled reactor	

capacitor(TCSC) and fix-capacitor thyristor controlled reactor (FC-TCR) except in the area of the equipments installation within the power system; in which the incorporation of shunt transformer with FC-TCR creates a remarkable compositional installation difference between the two FACTS equipments. In exception of these, the two controllers are structurally equivalent, apart from in minor situations where inclusion of some accessorial equipments are done on the basis of achievement of a desired purpose such as in harmonic control. Etc

(SVC) FC –	STRUC	TCSC	
TCR	SIMILARITIES		
1.Fundamentally, functional behavior of devices in electric sy upgrade the system b so as to enhance s	of FC-TCR ystem is to ous voltages	distinguisl activities electric improver power flo	pparent and hing operational s of a TCSC in c system is in nent of electric ow through line age supplement.
2.For FC-TCR ar devices in SVC resonance angle, $\alpha_r$ , cause problem w thyristor angles are n for susceptance ad	family, es does not hen the nanipulated	control a resonance power osci For that distant, maintain inductive power sys	on of thyristor angles into the e, $\alpha_{res}$ results illatory problem. a short angular $\Delta \alpha$ is usually ned within the plane to avoid stem oscillation ring the angle.
3. The range of firit variation mathematic within $90^{\circ} \le \alpha \ge 180^{\circ}$ for compensation for	cally exists or adequate	firitivariation is obtain $0^0 \leq 0^0$	ge of thyristor ng angle s mathematically ned within $\alpha \ge 90^{\circ}$ for compensation.
4. Variable reactance inverse of that of $\frac{1}{X_{eq}} = \frac{\pi \omega^2 LC - (\pi \pi \omega^2)}{-\pi \omega^2}$	TCSC:	equation is of that $X_{tcsc} = \frac{1}{\omega^2}$	able reactance s the the inverse of FC-TCR: $-\pi\omega L$ $2Lc-(\pi-2\alpha-Sin 2\alpha)$ $=X_{eq}$
5.The PI control out TCR Is $B_{SI}$	•		ntrol output for is <b>X_{tcsc}</b>
6.FC-TCR is installe with the syster			C is installed in th transmission lines.

### **III. CONCLUSION**

It is important to note that the two devices share the same structure just as briefly explained in the comparison table since the component composition of the two equipments are common. In the case of functional behavior and characteristics in terms of steady state condition evaluation; the two are obviously related considering the reactance of the TCR fragment which is the major points of similarity of the two; visa-vise, the operational effect on the system. With FC-TCR and other family members of static Var compensators, SVC; if the device is at the system bus voltage location and the operating voltage on the FACT elements is the bus voltage and a sinusoid; a furrier analytical evaluation with respect to reactor current waveform gives a clear view of TCR reactance at fundamental frequency to be similar with adjustable reactance expressed as

Thus, the equation can be further expanded to incorporate the capacitive and inductive reactance ratio in the overall effective reactance as shown below:

$$X_{eff(\alpha)} = \frac{X_{c} \cdot \pi \cdot \frac{1}{(X_{L}/X_{C})}}{Sin2\alpha - 2\alpha + \pi [2 - (1/(X_{c}/X_{L})]} \dots (10)$$
  
=  $\frac{(X_{C}^{2} \cdot \pi \cdot \frac{1}{X_{L}})}{Sin2\alpha - 2\alpha + \pi [2 - (1/(X_{c}/X_{L})]]}$   
=  $\frac{(2\pi^{2}FC^{2} \cdot \frac{1}{L})}{Sin2\alpha - 2\alpha + \pi [2 - (1/(C/L)]]} \dots (11)$   
Where,

 $2\pi fl = X_L$ , the inductive reactance of the reactor at fundamental frequency.  $1/2\pi fc = X_c$ , the capacitive reactance of the capacitor at fundamental frequency.  $\alpha$  = thyristor firing angle

f = system fundamental frequency

l = inductance of the reactor of the device

C = the device capacitor

The extent of the equipment functional participation is the decision of the thyristor firing angle whose range of variation is predetermined at the manufacturing stage. Adjustment of the controller through the angle enables the effective reactance variation so as to determine the degree of bus voltage changes assuming the basic circuit is connected in shunt with the bus.

Functionally FC-TCR is always installed on the bus through a step down transformer; (unlike TCSC device that occupies the line in series order) on the high voltage or extrahigh voltage side as the case may demand so as to reduce the device voltage to such a bearable capacity as 50kv and below

From the derived expression, the apparent similarity of FC-TCR reactance with TCSC reactance is very clear. It is inevitably imperative to know that the basic circuit is truly the same as well as their reactance when looking at the structure and component make-up; but differ in terms of function and position since the two devices do not maintain the same direction when connected on the system for reactive power provision. While the circuit is installed in series in a system for TCSC device to maintain the adjustable reactance  $(X_{adj}, or X_{eff}(\alpha)$  as the case may be) on the line; the same basic circuit maintains shunt position changing from series reactance to susceptance due to parallel/shunt position on the system bus; thereby, establishing a clearly drawn demarcating

line for distinction between the two devices . In the mode as seen above, the equivalent circuit can conveniently serve a major purpose of real power flow enhancement in assumption of series position with the line .Thus; voltage incorporated from the circuit, complements the natural series line voltage of the system to reinforce the network power transfer potential. On the other hand; the TCSC adjustable series reactance  $(X_{adj.} or X_{eff(\alpha)})$  automatically changes to FC-TCR adjustable susceptance  $(\frac{1}{X_{eff(\alpha)}} = B_{eff(\alpha)} \text{ or } \frac{1}{X_{adj.}} = B_{adj.})$ when connected in shunt to bus for exchange of reactive

power with the system in other to regulate bus voltages.

#### REFERENCES

- [1] A.L. Ara, S.A Nabavi Niayki. (2003) Comparison of the fact equipment operation I transmission and distribution system. E-mail: seyed@umz.ac.ir
- [2] N.G Hingorani, L.Gyugyi. (2000). understanding FACTS concept and technology of flexible AC transmission system
- [3] Gribel, J., et al., "Brazilian North-South Interconnection -Application of Thyristor-Controlled Series Compensation (TCSC) to Damp Inter Area Oscillation Mode," CIGRE Paper No. 14-101, 1998.
- "Static Synchronous Series [4] Gyugyi, L., et al., Compensator: A Solid-State Approach to the Series Compensation of Transmission Lines." IEEE Trans. On Power Delivery, vol. 12 no. 1, January 1997.